## NSN 5961-01-341-9622

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-341-9622 **Inclosure Material:** Metal **Overall Length:** Between 0.422 inches and 0.462 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.157 inches and 0.217 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 2.2 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

**Fiig:** A110a0